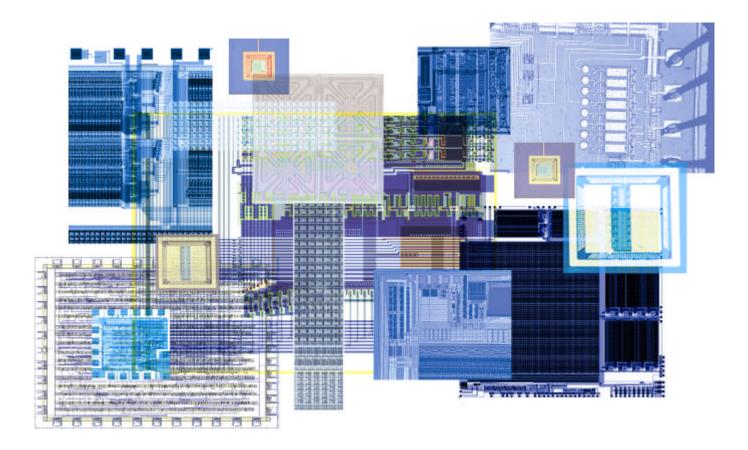
www.tanner.com/ces

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Pasadena, CA 91107 USA
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The MOSIS Service Hi-ESD Pad Library AMI C5N (0.5µ) Process

November 1998



Tanner Consulting & Engineering Services develops and delivers advanced ASIC and VLSI solutions for customers. We accomplish this through training programs, consulting services, field engineering and contracted design/development efforts.

Bi-Directional Pad

PADBIDIR

Description: Bi-Directional Pad with Buffer

Library: MOSIS AMI 050P Primitive Set: Tanner SCMOS.Cells

Tanner.TIB.Samples

TannerLb\scmos\mAMI05P.sdb Schematic: S-Edit File:

> Module: **PADBIDIR**

Mask layout: L-Edit TannerLb\scmos\mAMI05P.tdb File:

> Cell: **PADBIDIR**

Mapping Macros: GateSim: TannerLb\nettran\scmos\scms2sim.mac

> L-Edit/SPR: TannerLb\nettran\scmos\scms2tpr.mac

Logic Symbol	Logic Symbol Truth Tabl		n Table	е	
	PAD	OE	DI	DO	
	X	1	X	In	
	1	0	1	X	
PadBi di rHE_SCMOS	0	0	0	X	

N/A

Capacitance

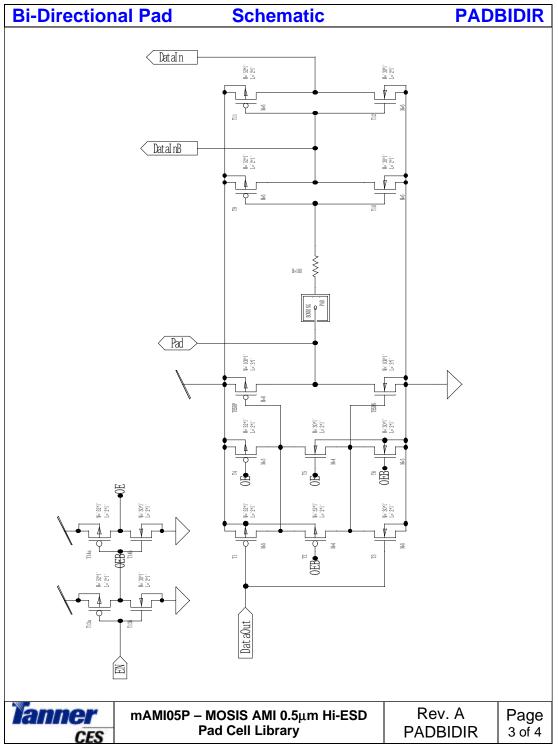
Height	Width	Area	Equivalent Gate	Drive
300 μ	90 μ	27000 μ ²	N/A	N/A

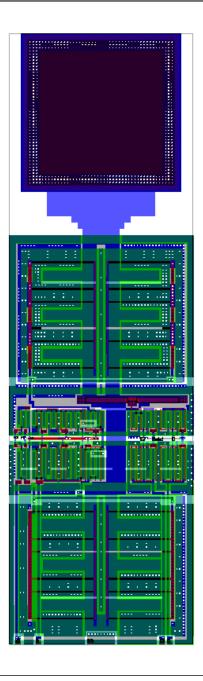
Logic Equation

See truth table

N/A **Delay Characteristics:**









Ground Pad PADGND

Description: Ground Pad

Library: MOSIS AMI 050P Primitive Set: Tanner SCMOS.Cells

Tanner.TIB.Samples

Schematic: S-Edit File: TannerLb\scmos\mAMI05P.sdb

Module: PADGND

Mask layout: L-Edit File: TannerLb\scmos\mAMI05P.tdb

Cell: PADGND

Mapping Macros: GateSim: TannerLb\nettran\scmos\scms2sim.mac

L-Edit/SPR: TannerLb\nettran\scmos\scms2tpr.mac

Logic Symbol	Truth Table	Capacitance
© PadGnd	N/A	N/A

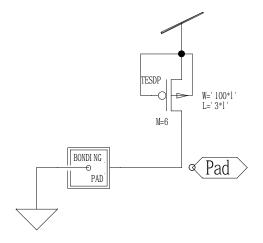
Height	Width	Area	Equivalent Gate	Drive
300 μ	90 μ	$27000 \mu^2$	N/A	N/A

Logic Equation		
N/A		

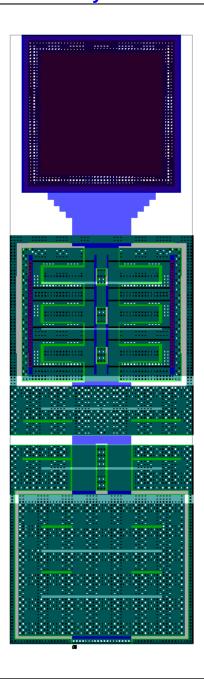
Delay Characteristics: N/A



PadGnd









Power Pad PADVDD

Description: Power Pad

Library: MOSIS AMI 050P Primitive Set: Tanner SCMOS.Cells

Tanner.TIB.Samples

Schematic: S-Edit File: TannerLb\scmos\mAMIP05.sdb

Module: PADVDD

Mask layout: L-Edit File: TannerLb\scmos\mAMIP05.tdb

Cell: PADVDD

Mapping Macros: GateSim: TannerLb\nettran\scmos\scms2sim.mac

L-Edit/SPR: TannerLb\nettran\scmos\scms2tpr.mac

Logic Symbol	Truth Table	Capacitance
© PadVdd	N/A	N/A

Height	Width	Area	Equivalent Gate	Drive
300 μ	90 μ	$27000 \mu^2$	N/A	N/A

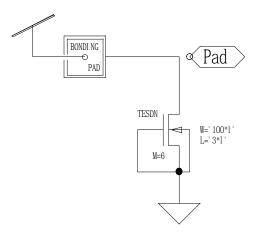
Logi	c Ec	Įuati	on

N/A

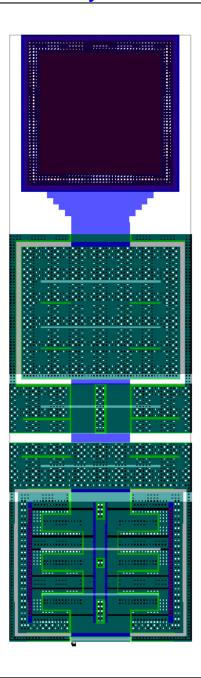
Delay Characteristics: N/A



PadVdd









mAMI05P - MOSIS AMI 0.5μm Hi-ESD Pad Cell Library Rev. A PADVDD

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